# **Amplifier Transistor PNP Silicon**

# COLLECTOR 3 BASE 1 EMITTER

### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit	
Collector-Emitter Voltage	VCEO	-100	Vdc	
Collector-Base Voltage	V <sub>CBO</sub>	-100	Vdc	
Emitter-Base Voltage	V <sub>EBO</sub>	-4.0	Vdc	
Collector Current — Continuous	IC	-600	mAdc	
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	625 5.0	mW mW/°C	
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	PD	1.5 12	Watts mW/°C	
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C	

# THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic		Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage(1) (IC = -1.0 mAdc, IB = 0)	V(BR)CEO	-100	_	Vdc
Collector-Base Breakdown Voltage (I <sub>C</sub> = -100 μAdc, I <sub>E</sub> = 0)	V(BR)CBO	-100	_	Vdc
Emitter-Base Breakdown Voltage ( $I_E = -10 \mu Adc$ , $I_C = 0$ )	V(BR)EBO	-4.0	_	Vdc
Collector Cutoff Current (V <sub>CB</sub> = -50 Vdc, I <sub>E</sub> = 0)	ІСВО	_	-1.0	μAdc
Emitter Cutoff Current (VEB = -3.0 Vdc, IC = 0)	I <sub>EBO</sub>	_	-100	nAdc

<sup>1.</sup> Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle = 2.0%.

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# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS(1)	<u>'</u>		•	
DC Current Gain <sup>(1)</sup> $(I_C = -50 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc})$	hFE	40	250	_
Collector-Emitter Saturation Voltage ( $I_C = -10 \text{ mAdc}$ , $I_B = -1.0 \text{ mAdc}$ ) ( $I_C = -50 \text{ mAdc}$ , $I_B = -5.0 \text{ mAdc}$ )	VCE(sat)	_ _	-0.25 -0.30	Vdc
Base-Emitter Saturation Voltage ( $I_C = -10$ mAdc, $I_B = -1.0$ mAdc) ( $I_C = -50$ mAdc, $I_B = -5.0$ mAdc)	V <sub>BE</sub> (sat)	_	-1.2 -1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Current-Gain — Bandwidth Product (I <sub>C</sub> = -10 mAdc, V <sub>CE</sub> = -10 Vdc, f = 20 MHz)	fT	60	_	MHz
Output Capacitance (V <sub>CB</sub> = -10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>obo</sub>	_	8.0	pF
Small–Signal Current Gain (I <sub>C</sub> = -1.0 mAdc, V <sub>CE</sub> = -10 Vdc, f = 1.0 kHz)	h <sub>fe</sub>	20	_	_

<sup>1.</sup> Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle = 2.0%.

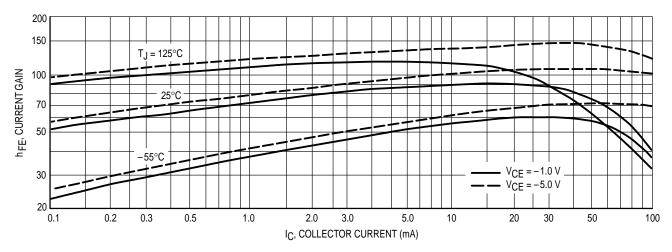


Figure 1. DC Current Gain

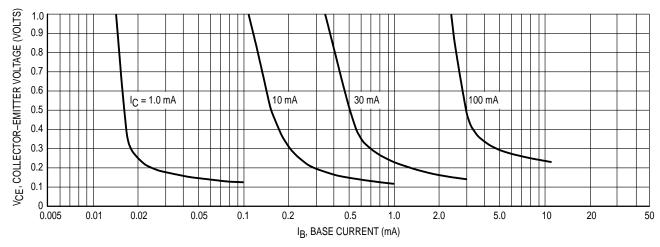


Figure 2. Collector Saturation Region

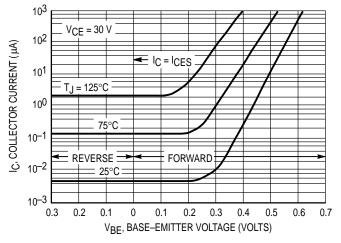


Figure 3. Collector Cut-Off Region

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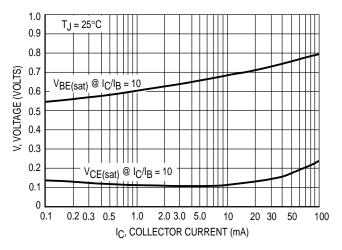


Figure 4. "On" Voltages

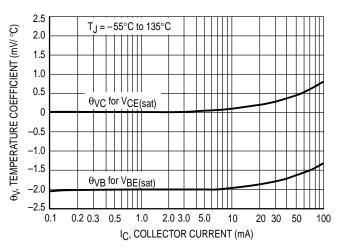
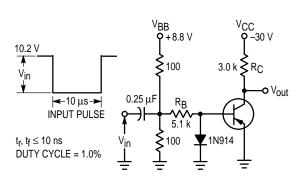


Figure 5. Temperature Coefficients



Values Shown are for I<sub>C</sub> @ 10 mA

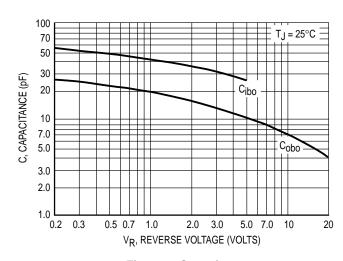
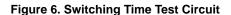


Figure 7. Capacitances



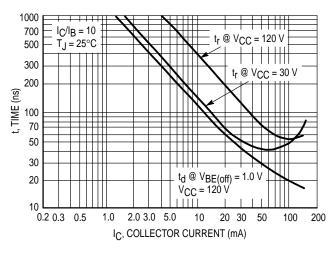


Figure 8. Turn-On Time

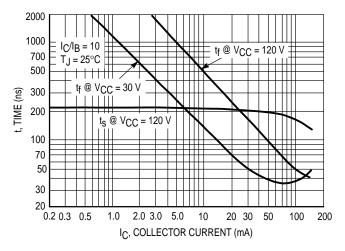
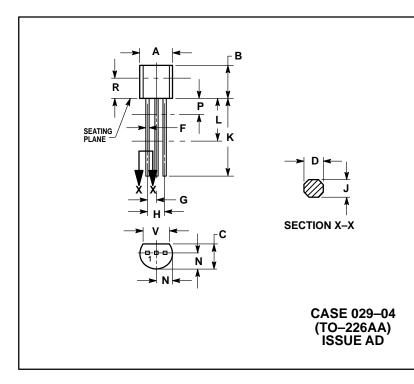


Figure 9. Turn-Off Time

# **PACKAGE DIMENSIONS**



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
  4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	LLIMETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.022	0.41	0.55	
F	0.016	0.019	0.41	0.48	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.115		2.93		
٧	0.135		3.43		

STYLE 1: PIN 1. EMITTER

2. BASE 3. COLLECTOR

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#### How to reach us:

**USA/EUROPE/Locations Not Listed**: Motorola Literature Distribution; P.O. Box 20912; Phoenix, Arizona 85036. 1–800–441–2447 or 602–303–5454

**MFAX**: RMFAX0@email.sps.mot.com – TOUCHTONE 602–244–6609 **INTERNET**: http://Design-NET.com

JAPAN: Nippon Motorola Ltd.; Tatsumi–SPD–JLDC, 6F Seibu–Butsuryu–Center, 3–14–2 Tatsumi Koto–Ku, Tokyo 135, Japan. 03–81–3521–8315

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298



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